## NSN 5961-01-029-9167

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-9167 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.140 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 reverse voltage, peak **Current Rating Per Characteristic:** 50.00 microamperes forward current, average major **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release2000 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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